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Two-photon absorption in two-dimensional materials: The case of hexagonal boron nitride

Claudio Attaccalite,^{1,2} Myrta Grüning,^{3,4} Hakim Amara,⁵ Sylvain Latil,⁶ and François Ducastelle⁵

¹*CNRS/Aix-Marseille Université, Centre Interdisciplinaire de Nanoscience de Marseille UMR 7325 Campus de Luminy, 13288 Marseille Cedex 9, France*

²*University of Rome Tor Vergata, Rome, Italy*

³*School of Mathematics and Physics, Queen's University Belfast, Belfast BT7 1NN, Northern Ireland, UK*

⁴*European Theoretical Spectroscopy Facilities (ETSF)*

⁵*LEM, UMR 104 CNRS-ONERA, Université Paris Saclay F-92322 Châtillon, France*

⁶*SPEC, CEA, CNRS, Université Paris-Saclay, CEA Saclay 91191 Gif sur Yvette, France*

We calculate the two-photon absorption in bulk and single layer hexagonal boron nitride (*h*-BN) both by an *ab initio* real-time Bethe-Salpeter approach and by a the real-space solution of the excitonic problem in tight-binding formalism. The two-photon absorption obeys different selection rules from those governing linear optics and therefore provides complementary information on the electronic excitations of *h*-BN. Combining the results from the simulations with an analysis of the crystal symmetries, we show that two-photon absorption is able to probe the lowest energy *1s* state in the single layer *h*-BN and the lowest degenerate exciton of bulk *h*-BN. This result indicates that in *h*-BN multilayer stackings with inversion symmetry one can measure the Davydov splitting by means of a combination of one and two-photons excitations. The same analysis can be applied to other two-dimensional materials with the same point-group symmetry—such as the transition metal chalcogenides.

I. INTRODUCTION

Two-photon absorption (TPA) is a nonlinear optical process in which the absorption of two photons excites a system to a higher energy electronic state. Nonlinear optical properties of two-dimensional (2D) crystals, and as such the TPA, have been recently the object of several experiments. For example, a giant TPA has been reported^{1,2} for transition metal dichalcogenides (TMDs) which has been attributed to the peculiar optical properties of 2D crystals; further, TPA has been used to image single quantum emitters embedded in a *h*-BN multilayer flake³; moreover in another study on TMDs, TPA has been used to probe excited states which are dark in linear optics.⁴ In fact, two-photon transitions obey selection rules distinct from those governing linear excitation processes and thereby provide complementary insights into the electronic structure of excited states.^{5,6} In particular it is frequently argued that one-photon processes are only allowed for excitons of *s* symmetry whereas *p* states can be observed in TPA. These rules can be derived within a continuous hydrogenic model for excitons where full rotational symmetry is assumed. They have been invoked to analyze the excitonic effects observed in carbon nanotubes,⁷ and also recently in bulk *h*-BN.⁸ Though it is recognized that these rules are not generally valid if the genuine crystalline symmetry is taken into account, it is claimed they can at least guide interpretations in terms of high or low oscillator strength.⁹ For 2D materials,¹⁰ excitonic effects are strong and the exciton wave functions are fairly localized, so that the low threefold symmetry plays an important role.¹¹ Although it has been first argued that the usual selection rules based on the hydrogenic model are also valid,¹² more accurate studies have shown that this is actually not the case, for one-photon as well

as for two-photon processes.^{13–16}

Here we analyze the case of the *h*-BN single layer and bulk, which have the same lattice symmetry as the TMDs and very strongly bound excitons. We combine tight-binding (TB) calculations¹⁴ of the two-photon transition probability with sophisticated *ab initio* real-time Bethe-Salpeter simulations¹⁷ of the two-photon resonance third-order susceptibility. This combination is a unique feature of this work: on the one hand the TB calculations allow us to identify the symmetry properties of the excitons, on the other hand the *ab initio* real-time Bethe-Salpeter (RT-BSE) simulations provide the TPA spectra—one of the first *ab initio* TPA spectra at this level of theory¹⁸—which can be compared quantitatively with experiments. From these two very different approaches (TB and RT-BSE), we consistently show that the TPA is able to probe the lowest *1s* exciton in the bulk and single layer *h*-BN.

In Sec. II we discuss the choice of *h*-BN as a case study and describe the tight-binding modeling of its electronic and optical properties. In Sec. III we detail how to obtain the TPA within both TB and RT-BSE: within the TB we expand the real-space formalism to the second order in the external perturbation and within the RT-BSE we introduce a post-processing technique based on Richardson extrapolation to extract the two-photon resonant third-order susceptibility, and thus the TPA, from the real-time polarization. We then show and compare the results of the *ab initio* real-time simulations (Sec. IV A) and of the TB calculations (Sec. IV B) for the single layer *h*-BN. We also contrast the case of the single layer with the bulk, highlighting the role of the inversion symmetry. Finally, we discuss the selection rules for one- and two-photon processes and on the basis of our results we clarify few recent experimental works on nonlinear optical properties of 2D crystals and bulk *h*-BN (Sec. IV C).

II. ELECTRONIC, OPTICAL PROPERTIES AND TIGHT BINDING MODEL OF h -BN

A. Choice of the system

We have chosen h -BN monolayer as a case study for several reasons. One reason is the abundance of experimental studies (luminescence,^{8,19–25} X-rays,^{26,27} or electron energy loss spectroscopy.^{28,29}) on the electronic and optical properties of both the bulk and the single layer. These studies, supported by theoretical investigations,^{30–36} have shown that h -BN is an indirect band gap insulator whose optical absorption spectrum is dominated by strongly bound excitons. Then, the electronic structures of the h -BN monolayer and of the bulk structure are fairly well known—which is convenient for the tight-binding model.^{30,37} A h -BN monolayer is simply the honeycomb lattice where B and N atoms alternate on the hexagons. The bands close to the gap are built from the π states. In the case of the monolayer, there are just a single valence π band and a conduction π^* band which are nearly parallel along the KM direction of the Brillouin zone. The gap is direct at K point and about 7 eV.¹⁴

It is of interest as well to compare the TPA in the single layer and in the layered bulk system. The stablest bulk structure corresponds to a so-called AA' stacking where B and N atoms alternate along lines parallel to the stacking axis. The periodicity along this axis is twice the inter-planar distance and the lattice parameters used in our simulation are $a = 2.5 \text{ \AA}$ and $c/a = 2.6$.³⁸ In the bulk, there are then two π and two π^* bands and the gap becomes indirect between a point close to K (valence band) and M (conduction band).³⁹

Another reason for choosing h -BN is the strong bound excitons in the absorption spectrum of both the monolayer and the bulk^{14,31,32} since as mentioned before, we expect the effect of the low threefold symmetry to be more visible for very localized excitons. More practically, spectral features corresponding to strongly localized exciton converge easily with the numerical parameters within the *ab initio* framework allowing for accurate and not too cumbersome calculations. Furthermore, while in the absorption spectrum of the single layer there is only a pair of degenerate excitons,¹⁴ in the absorption spectrum of bulk h -BN there are two degenerate pairs of excitons: one dark pair, which is the lowest in energy, and one bright pair (Davydov splitting).^{30,32} Probing the lowest excitons in bulk h -BN remains a challenge. We expect that since the system has an inversion symmetry, the dark states in the absorption become bright in the TPA and *vice versa*, so that it may be possible to probe the lowest excitons in the bulk h -BN in TPA. In Sec.IV we show that this is indeed the case.

Finally, other systems of interest, such as the TMDs, have the same lattice symmetry, so that results depending on the symmetry properties can be generalised or can be used as a starting point when studying those systems.

B. Tight-binding model

Many TB studies are dedicated to the electronic and optical properties of h -BN (see e.g. Refs.14 and 40). Here, we used a simple model that describes top valence and bottom conduction bands close to the gap, and which is stable to catch the most relevant physics of optical excitation in h -BN. It turns out that the valence states close to the gap are almost completely centered on the nitrogen sites whereas the conduction states are centered on the boron sites. For the monolayer this has allowed us to derive a very simple TB model characterised by two parameters: an atomic parameter Δ related to the atomic levels, $+\Delta$ for boron, and $-\Delta$ for nitrogen, and a transfer integral between first neighbors $-t, t > 0$. For these parameters we used the same values of Ref. 14. In this model the direct gap is exactly equal to 2Δ . Close to the gap the electronic structure can be simplified and the electrons in the conduction band (valence band) can be considered as moving on the B (N) sublattice with an effective transfer integral equal to $t^2/2\Delta$. The Wannier states associated with the π and π^* bands are then mainly localized on N and B sublattices with small components $\pm(t/2\Delta)$ on the other ones. This discrete TB model has a continuous counterpart when expanding the equations close to K in reciprocal space. The band structure is then described within a Dirac model for massless 2D electrons for graphene or continuous massive Dirac model for h -BN. The simplest extension of the 2D TB model to bulk h -BN consists in introducing transfer integrals between nearest neighbors along the stacking axis.^{34,39}

C. One-photon absorption for independent single particles

To first order (one-photon processes), the coupling with the electromagnetic field is described using the hamiltonian $H_{I1} = -e\mathbf{p}\cdot\mathbf{A}/m$, where \mathbf{A} is the vector potential varying as $e^{-i\omega t}$. To this order, $\mathbf{p}/m = \mathbf{v} = \frac{1}{i\hbar}[\mathbf{r}, H]$, where \mathbf{v} is the velocity operator and H is the hamiltonian of the unperturbed system. Using the tight-binding scheme, where $|\mathbf{n}\rangle$ denotes a π state at site \mathbf{n} , we have $\mathbf{v}_{\mathbf{n}\mathbf{m}} = \langle \mathbf{n} | \mathbf{v} | \mathbf{m} \rangle = (\mathbf{n} - \mathbf{m})t_{\mathbf{n}\mathbf{m}}/i\hbar$, where $t_{\mathbf{n}\mathbf{m}}$ is the transfer integral between sites \mathbf{n} and \mathbf{m} . Using our simple model for the h -BN sheet, we keep only first neighbor integrals $-t$ and the matrix element couples valence states $|\mathbf{m}_v\rangle$ to conduction states $|\mathbf{n}_c\rangle$. Actually, as mentioned above, the atomic states should be replaced by Wannier states:

$$|\mathbf{m}_v\rangle_w \simeq |\mathbf{m}_N\rangle + \frac{t}{2\Delta} \sum_{\tau} |\mathbf{m}_N + \tau\rangle \quad (1)$$

$$|\mathbf{n}_c\rangle_w \simeq |\mathbf{n}_B\rangle - \frac{t}{2\Delta} \sum_{\tau} |\mathbf{n}_B - \tau\rangle, \quad (2)$$

where $|\mathbf{m}_N\rangle$ and $|\mathbf{n}_B\rangle$ denote the genuine atomic states centered on the N and B atoms, and where the three

$\boldsymbol{\tau}$ vectors are the first neighbor vectors $\mathbf{n}_B - \mathbf{m}_N$. The corresponding Bloch functions are given by:

$$|\mathbf{k}_v\rangle \simeq |\mathbf{k}_N\rangle + \frac{t}{2\Delta} f^*(\mathbf{k}) |\mathbf{k}_B\rangle \quad (3)$$

$$|\mathbf{k}_c\rangle \simeq |\mathbf{k}_B\rangle - \frac{t}{2\Delta} f(\mathbf{k}) |\mathbf{k}_N\rangle, \quad (4)$$

where the $|\mathbf{k}_{N(B)}\rangle$ are the Bloch functions built from the atomic orbitals and $f(\mathbf{k}) = \sum_{\boldsymbol{\tau}} e^{i\mathbf{k}\cdot\boldsymbol{\tau}}$. At lowest order in t/Δ we have that $\langle \mathbf{k}_c | \mathbf{v} | \mathbf{k}_v \rangle \simeq \langle \mathbf{k}_B | \mathbf{v} | \mathbf{k}_N \rangle$. Then following Ref. 14 in the limit $\mathbf{k} \rightarrow \mathbf{K}$ we obtain:

$$\langle \mathbf{k}_c | \mathbf{v} \cdot \mathbf{e} | \mathbf{k}_v \rangle \simeq \langle \pm \mathbf{K}_c | \mathbf{v} \cdot \mathbf{e} | \pm \mathbf{K}_v \rangle \simeq v_F (e_x \pm i e_y), \quad (5)$$

where $v_F = \frac{3}{2} a_{bn} t$ and a_{bn} is the distance between first neighbor B and N atoms. \mathbf{e} is the light polarization vector and $\pm \mathbf{K}_c$ are the wave functions at the $\pm K$ points. Notice that the optical coupling between valence and conduction bands is not related here to the symmetry of the π states of nitrogen and boron. Indeed, when considering polarization vectors within the sheet plane, they behave as s states. The coupling is due to the fact that the Wannier functions of the π and π^* bands are centered on different sublattices.

Within a one-particle model and neglecting the photon wave vector, the one-photon absorption is proportional to the transition probability W given by the Fermi golden rule:

$$W = \frac{2\pi}{\hbar} \frac{e^2}{\omega^2} (\mathcal{E}/2)^2 \sum_{\mathbf{k}} |\langle \mathbf{k}_c | \mathbf{v} \cdot \mathbf{e} | \mathbf{k}_v \rangle|^2 \delta(E_{\mathbf{k}_c} - E_{\mathbf{k}_v} - \hbar\omega),$$

where \mathcal{E} is the electrical field amplitude. In our model the valence and conduction bands are symmetric, $E_{\mathbf{k}_v} = -E_{\mathbf{k}_c}$, so that $E_{\mathbf{k}_c} - E_{\mathbf{k}_v} \simeq 2\Delta + \frac{t^2}{\Delta} |f(\mathbf{k})|^2$, where $|f(\mathbf{k})|^2$ is the band energy of a triangular lattice with transfer integrals equal to t^2/Δ and centered on $2\Delta + 3t^2/\Delta$.¹⁴ Neglecting the dependence on \mathbf{k} of the matrix element, and replacing $E = \hbar\omega$ by 2Δ close to the gap, we recover the usual formula for the absorption, proportional to the joint density of states.¹⁴

D. Excitons

In the presence of electron-hole interactions, excitonic effects come into play. They are usually treated using a Bethe Salpeter formalism, which, within our TB formalism, can be reduced to an effective Wannier-Schrödinger equation for electron-hole pairs. In the present formulation, we are not including the exchange term, therefore the singlet and triplet excitons are degenerate. This fact does not affect our results since triplet excitations are dark due the spin selection rules and they do not contribute to the linear and non-linear response. Regarding the effect of the exchange term on the singlet exciton this is negligible at zero momentum (while it becomes important at finite momentum and for higher excitons).^{14,41}

Let $|\Phi\rangle$ be an excitonic state. In our model for the monolayer, it can be written as:

$$|\Phi\rangle = \sum_{\mathbf{k}} \Phi_{\mathbf{k}} a_{\mathbf{k}_c}^+ a_{\mathbf{k}_v} |\emptyset\rangle, \quad (6)$$

where $a_{\mathbf{k}_c}^+$ and $a_{\mathbf{k}_v}$ are the usual creation and annihilation operators for conduction and valence electrons and $|\emptyset\rangle$ is the unperturbed ground state.

The exciton wavefunction [Eq. (6)] can be found from the solution of the so-called Bethe Salpeter equation which is just an effective Schrödinger equation for electron-hole pairs:

$$(E_{\mathbf{k}_c} - E_{\mathbf{k}_v}) \Phi_{\mathbf{k}vc} + \sum_{\mathbf{k}'v'c'} \langle \mathbf{k}vc | K_{eh} | \mathbf{k}'v'c' \rangle \Phi_{\mathbf{k}'v'c'} = E \Phi_{\mathbf{k}vc}.$$

In this equation, $E_{\mathbf{k}_c} - E_{\mathbf{k}_v}$ plays the part of a band energy. The interaction term K_{eh} contains the direct Coulomb contribution. In real space the excitonic hamiltonian H_{eh} reads:

$$H_{eh}^{\mathbf{R},\mathbf{R}'} = \langle \mathbf{R} | H_{eh}^0 | \mathbf{R}' \rangle + U_{\mathbf{R}} \delta_{\mathbf{R},\mathbf{R}'}, \quad (7)$$

where $U_{\mathbf{R}}$ is represented by a Keldysh potential, that has been parametrized as described in Ref. 14.

From the solution of [Eq. (7)] we can calculate the matrix element between the exciton state $\langle \Phi |$ and the ground state $|\emptyset\rangle$, that are the ones entering the linear response.⁴² Using the Wannier basis for electron and hole wave-functions it is possible to express these matrix elements as:¹⁴

$$W_{\Phi} \equiv \langle \Phi | \mathbf{e} \cdot \mathbf{v} | \emptyset \rangle = (it/\hbar) \sum_{\boldsymbol{\tau}} \mathbf{e} \cdot \boldsymbol{\tau} \langle \Phi | \boldsymbol{\tau} \rangle. \quad (8)$$

If we define a dipole matrix element $\mathbf{d}_{\Phi} = \sum_{\boldsymbol{\tau}} \boldsymbol{\tau} \langle \boldsymbol{\tau} | \Phi \rangle$, the transition probability associated with exciton Φ is given by:

$$P_{\Phi} = \frac{2\pi}{\hbar} \frac{e^2 (\mathcal{E}/2)^2 t^2}{E^2} |\mathbf{e} \cdot \mathbf{d}_{\Phi}|^2 \delta(E - E_{\Phi}), \quad (9)$$

where E_{Φ} is the exciton energy. Since $E_{\Phi} \sim \Delta$, this probability is of order $(t/\Delta)^2$. In the case of the BN monolayer, the point symmetry is that of the C_{3v} group and vectors transform as the two-dimensional E representation of this group. The exciton is therefore “bright”, $\mathbf{d}_{\Phi} \neq 0$, if $|\Phi\rangle$ also transforms as E . Notice also that only the local components of the wave function are involved in \mathbf{d}_{Φ} . This is the discrete equivalent of the classical Elliott theory: Within a continuous model the matrix element is proportional to $\Phi(\mathbf{r} = 0)$.^{43,44} In our case, the ground state exciton of the monolayer, discussed in detail in Ref.[14], does transform as E . If the position of the hole is fixed at the origin, the exciton wave function extends principally on the first neighbors and its oscillator strength is very large. $\Phi_{\alpha}^{\pm} \propto e^{\pm i(2\alpha\pi/3)}$, these two circularly polarized components can be associated with the one-dimensional representations of the C_3 group at K and K' points.

Finally the probability transition can be calculated using the Green function $G(z) = (z - H_{eh})^{-1}$, as solution of $\langle \emptyset | \mathbf{v} G(z) \mathbf{v} | \emptyset \rangle$, for more detail see Ref. 45.

III. TWO-PHOTON ABSORPTION

The TPA is related to the nonlinearity in the attenuation of a laser beam. Considering the intensity I of a beam propagating along \hat{z} , at the lowest order beyond the linear regime, the attenuation is a nonlinear function of I :

$$\frac{dI}{dz} = -\alpha I - \beta I^2, \quad (10)$$

where α is the linear absorption coefficient, and β is the two-photon absorption coefficient (see e.g. Ref.[46])

In what follows, we detail how we evaluate the TPA from either the third-order susceptibility extracted from *ab initio* real-time dynamics (Sec. III A) and from the transition probability of a two-photon process within a second-order perturbation treatment (Sec. III B 1).

A. Nonlinear susceptibilities from *ab initio* real-time dynamics

The TPA coefficient in Eq. (10) is related to the imaginary part of the third-order response function $\chi^{(3)}$ ^{46,47}:

$$\beta(\omega) = \frac{3\omega}{2\epsilon_0 c^2 n_0^2(\omega)} \text{Im} \left[\chi^{(3)}(-\omega; \omega, \omega, -\omega) \right]. \quad (11)$$

where $n_0(\omega)$ is the refractive index. In two-photon measurements, the incoming laser frequency ω is set around half of the excited state energy ω_0 we want to probe $2\omega \simeq \omega_0$.

In this frequency region, well below the band gap, $n_0(\omega)$ is positive, monotonic and slowly varying, therefore the peaks of $\beta(\omega)$ originates only from the imaginary part of $\chi^{(3)}$, that is the quantity we will extract from the real-time simulations.¹⁷ In the real-time simulations, the electronic system is excited by a monochromatic homogeneous field. The time-evolution of the system is given by the following equation of motion for the valence band states,

$$i\hbar \frac{d}{dt} |v_{m\mathbf{k}}\rangle = \left(H_{\mathbf{k}}^{\text{MB}} + i\mathcal{E} \cdot \tilde{\partial}_{\mathbf{k}} \right) |v_{m\mathbf{k}}\rangle, \quad (12)$$

where $|v_{m\mathbf{k}}\rangle$ is the periodic part of the Bloch states. In the r.h.s. of Eq. (12), $H_{\mathbf{k}}^{\text{MB}}$ is the effective Hamiltonian derived from many-body theory that includes both the electron-hole interaction and local field effects. The specific form of $H_{\mathbf{k}}^{\text{MB}}$ is presented below. The second term in Eq. (12), $\mathcal{E} \cdot \tilde{\partial}_{\mathbf{k}}$, describes the coupling with the external field \mathcal{E} in the dipole approximation. As we imposed Born-von Kármán periodic boundary conditions, the coupling takes the form of a \mathbf{k} -derivative operator $\tilde{\partial}_{\mathbf{k}}$. The tilde indicates that the operator is “gauge covariant” and guarantees that the solutions of Eq. (12) are invariant under unitary rotations among occupied states at \mathbf{k} (see Ref. [48] for more details).

We notice that we adopt here the length gauge, which presents several advantages for *ab initio* simulations.¹⁷

Comparing with the velocity gauge approach—that is used in the tight-binding model—the second term of Eq. (12) includes both the \mathbf{A} and \mathbf{A}^2 contributions present in the velocity gauge. The two gauges are equivalent as shown in Appendix A.

From the evolution of $|v_{m\mathbf{k}}\rangle$ in Eq. (12) we calculate the real-time polarization \mathbf{P}_{\parallel} along the lattice vector \mathbf{a} as

$$\mathbf{P}_{\parallel} = -\frac{ef|\mathbf{a}|}{2\pi\Omega_c} \text{Im} \log \prod_{\mathbf{k}}^{N_{\mathbf{k}}-1} \det S(\mathbf{k}, \mathbf{k} + \mathbf{q}), \quad (13)$$

where $S(\mathbf{k}, \mathbf{k} + \mathbf{q})$ is the overlap matrix between the valence states $|v_{n\mathbf{k}}\rangle$ and $|v_{m\mathbf{k}+\mathbf{q}}\rangle$, Ω_c is the unit cell volume, f is the spin degeneracy, $N_{\mathbf{k}}$ is the number of \mathbf{k} points along the polarization direction, and $\mathbf{q} = 2\pi/(N_{\mathbf{k}}\mathbf{a})$.

The polarization can be expanded in a power series of the incoming field \mathcal{E}_j as:

$$\mathbf{P}_i = \chi_{ij}^{(1)} \mathcal{E}_j + \chi_{ijk}^{(2)} \mathcal{E}_j \mathcal{E}_k + \chi_{ijkl}^{(3)} \mathcal{E}_j \mathcal{E}_k \mathcal{E}_l + O(\mathcal{E}^4), \quad (14)$$

where the coefficients $\chi^{(i)}$ are a function of the frequencies of the perturbing fields and of the outgoing polarization. As explained above, the two-photon absorption is proportional to the imaginary part of the two-photon resonance third-order susceptibility $\chi_{ijkl}^{(3)}(-\omega; \omega, \omega, -\omega)$: *i.e.* the outgoing polarization has the same frequency ω of the incoming laser field, as a result of the absorption of two and the emission of one virtual photons.

In order to extract the $\chi^{(3)}$ coefficients we resort to a technique similar to Richardson extrapolation.⁴⁹ In practice, we perform three different simulations with the incoming electric field at frequency ω and intensities corresponding to the amplitudes \mathcal{E} , $\mathcal{E}/2$ and $\mathcal{E}/4$. The polarization resulting from each simulation can be expanded in the field as:

$$\mathbf{P}(\mathcal{E}) = \chi^{(1)} \mathcal{E} + \chi^{(2)} \mathcal{E}^2 + \chi^{(3)} \mathcal{E}^3 + O(\mathcal{E}^4), \quad (15)$$

$$\mathbf{P}\left(\frac{\mathcal{E}}{2}\right) = \chi^{(1)} \frac{\mathcal{E}}{2} + \chi^{(2)} \frac{\mathcal{E}^2}{4} + \chi^{(3)} \frac{\mathcal{E}^3}{8} + O(\mathcal{E}^4), \quad (16)$$

$$\mathbf{P}\left(\frac{\mathcal{E}}{4}\right) = \chi^{(1)} \frac{\mathcal{E}}{4} + \chi^{(2)} \frac{\mathcal{E}^2}{16} + \chi^{(3)} \frac{\mathcal{E}^3}{64} + O(\mathcal{E}^4). \quad (17)$$

Then we combine the three polarizations so to cancel out the linear and quadratic contributions and we obtain:

$$\chi^{(3)} = \frac{8\mathbf{P}(\mathcal{E}) - 6\mathbf{P}\left(\frac{\mathcal{E}}{2}\right) + 8\mathbf{P}\left(\frac{\mathcal{E}}{4}\right)}{\mathcal{E}^3}. \quad (18)$$

The calculation is repeated for all ω in the desired range of frequencies.

The level of approximation of the so-calculated susceptibilities depends of the effective Hamiltonian that appears in the r.h.s. of Eq. (12). Here we work in the so-called real-time Bethe-Salpeter framework that was introduced in Ref.[50]. In this framework the Hamiltonian $H_{\mathbf{k}}^{\text{MB}}$ reads:

$$H_{\mathbf{k}}^{\text{MB}} \equiv H_{\mathbf{k}}^{\text{KS}} + \Delta H_{\mathbf{k}} + V_h(\mathbf{r})[\Delta\rho] + \Sigma_{\text{SEX}}[\Delta\gamma], \quad (19)$$

where $H_{\mathbf{k}}^{\text{KS}}$ is the Hamiltonian of the unperturbed (zero-field) Kohn-Sham system,⁵¹ $\Delta H_{\mathbf{k}}$ is the scissor operator that has been applied to the Kohn-Sham eigenvalues, the term $V_h(\mathbf{r})[\Delta\rho]$ is the real-time Hartree potential¹⁷ and is responsible for the local-field effects⁵² originating from system inhomogeneities. The term Σ_{SEX} is the screened-exchange self-energy that accounts for the electron-hole interaction,⁵² and is given by the convolution between the screened interaction W and $\Delta\gamma$. In the same equation:

$$\Delta\rho \equiv \rho(\mathbf{r}; t) - \rho(\mathbf{r}; t = 0)$$

is the variation of the electronic density and:

$$\Delta\gamma \equiv \gamma(\mathbf{r}, \mathbf{r}'; t) - \gamma(\mathbf{r}, \mathbf{r}'; t = 0)$$

is the variation of the density matrix induced by the external field \mathcal{E} .

In the limit of small perturbation Eq. (19) and Eq. (12) reproduce the optical absorption calculated with the standard $GW + \text{BSE}$ approach,⁵² as shown both analytically and numerically in Ref. [50].

B. Tight binding model

In tight-binding the second order (two-photon processes) appears in the development of $(\mathbf{p} - e\mathbf{A})^2/2m$. In second order perturbation theory with respect to \mathbf{A} , there are two terms. The first one is related to the linear term $(\mathbf{p} - e\mathbf{A})$ treated in a second order perturbation theory, and the second one comes from the A^2 term treated to first order. The latter one is frequently considered as non relevant in the optical regime, which is not the case here as explained below. Let us begin with the first contribution.

1. Second order perturbation theory

To second order, the transition probability $P_{i \rightarrow f}$ from an initial state $|i\rangle$ towards a final state $|f\rangle$ is given by:⁵³

$$P_{i \rightarrow f} = \frac{2\pi}{\hbar} \left| \frac{1}{4} \sum_{j \neq i, f} \frac{W_{fj} W_{ji}}{E_i - E_j + \hbar\omega} \right|^2 \delta(E_f - E_i - 2\hbar\omega), \quad (20)$$

where W_{ij} is the one-photon matrix element towards the intermediate state j . A convenient approximation consists here to replace E_j by a mean energy between the initial energy and the exciton levels close to the bottom of the conduction band.^{12,54,55} The sum in the numerator can then be freely performed, and we are back to a situation similar to the first order calculation, where now the relevant matrix element is equal to $\langle f | W^2 | i \rangle$. Since we are looking at transition close to the gap, $\hbar\omega \sim \Delta$, and the denominator is also of order Δ . The relevant matrix element is equal to $\langle \Phi | (\mathbf{v} \cdot \mathbf{e})(\mathbf{v} \cdot \mathbf{e}) | \emptyset \rangle$. As seen above,

the first velocity operator operating on the ground state generates electron-hole states. Therefore, the second one couples different electron-hole states. Since it is related to the kinetic energy part, it operates separately on the electron state and on the hole state, and therefore gives contributions proportional to the velocity of the one-particle states. The corresponding matrix elements in real space are equal to $-\frac{i}{\hbar} \frac{t^2}{\Delta} \mathbf{a}$, where \mathbf{a} is a first neighbor distance on the triangular lattice. The final complete matrix element $\langle \Phi | (\mathbf{v} \cdot \mathbf{e})(\mathbf{v} \cdot \mathbf{e}) | \emptyset \rangle / \Delta$ is therefore of order t^3 / Δ^2 . There is no reason that it vanishes identically for the ground state exciton. Actually the (tensorial) product of velocity operators transform as $E \times E$ which also contains E . In the continuous limit however, it can be shown¹² that $\langle \Phi | \mathbf{v} \otimes \mathbf{v} | \emptyset \rangle \sim \nabla \Phi(\mathbf{r})|_{r=0}$, which implies that only p states are bright. We are in a typical situation where precise selection rules based on the exact crystalline symmetry allow transitions which become forbidden if an approximate (higher) spherical symmetry is assumed.⁹

2. A^2 term

In principle the A^2 term is local and its influence is negligible in the optical regime where the wave length is much larger than interatomic distances. At least is this true when using the full hamiltonian. In band theory we project the hamiltonian on the subspace defined by the number of bands taken into account, and the correct method to include gauge-invariant coupling with the electromagnetic field is to make the so-called Peierls substitution. This generates non-local coupling at all orders in \mathbf{A} . More precisely in our case, we make the substitution:

$$t_{\mathbf{nm}} \rightarrow t_{\mathbf{nm}} e^{i\mathbf{e}(\mathbf{n}-\mathbf{m}) \cdot \mathbf{A} / \hbar}. \quad (21)$$

To first order, we can check that this generates the coupling H_{I1} used above, *i.e.* :

$$\langle \mathbf{n} | H_{I1} | \mathbf{m} \rangle = i \left(\frac{e}{\hbar} \right) (\mathbf{m} - \mathbf{n}) \cdot \mathbf{A} t_{\mathbf{nm}}, \quad (22)$$

and therefore:

$$\langle \emptyset | H_{I1} | \Phi^\pm \rangle = i \frac{eAt}{\hbar} \sum_{\boldsymbol{\tau}} (\boldsymbol{\tau} \cdot \mathbf{e}) \Phi_{\boldsymbol{\tau}}^\pm \quad (23)$$

$$\sum_{\boldsymbol{\tau}} (\boldsymbol{\tau} \cdot \mathbf{e}) \Phi_{\boldsymbol{\tau}}^\pm = \mathbf{e} \cdot \mathbf{d}_{\Phi^\pm} = -\frac{3}{2} a_{bn} (e_x \pm ie_y) |\Phi_{\boldsymbol{\tau}}^\pm|, \quad (24)$$

where $a_{bn} = |\boldsymbol{\tau}|$ and $\Phi_{\boldsymbol{\tau}}^\pm$ is the amplitude $\langle \boldsymbol{\tau} | \Phi^\pm \rangle$ of the circularly polarized state defined previously. To second order, we obtain:

$$\langle \mathbf{n} | H_{I2} | \mathbf{m} \rangle = -\frac{1}{2} \left(\frac{e}{\hbar} \right)^2 [(\mathbf{m} - \mathbf{n}) \cdot \mathbf{A}]^2 t_{\mathbf{nm}},$$

from which we deduce that:

$$\langle \emptyset | H_{I2} | \Phi_{\pm} \rangle = -\frac{1}{2} \left(\frac{eA}{\hbar} \right)^2 t \sum_{\tau} (\tau \cdot \mathbf{e})^2 \Phi_{\tau}^{\pm} \quad (25)$$

$$\sum_{\tau} (\tau \cdot \mathbf{e})^2 \langle \tau | \Phi_{+} \rangle = \mathbf{e} \cdot \bar{\mathbf{q}} \cdot \mathbf{e} = \frac{3}{8} a_{bn}^2 (e_x - i e_y)^2 |\Phi_{\tau}^{\pm}|, \quad (26)$$

where $\bar{\mathbf{q}}_{\Phi_{\pm}} = \sum_{\tau} (\tau \otimes \tau) \Phi_{\tau}^{\pm}$ is a quadrupolar matrix element.

The last result is remarkable. It shows first that the matrix element is similar to that of the first order term and therefore that the corresponding two-photon process should be strongly visible. Then we see that the favored circular polarization for the two-photon process is the opposite of that of the one-photon process. Finally this direct contribution to first order in A^2 is stronger than the contribution discussed above coming from the second order perturbation theory. The latter one is of order t^2/Δ^2 less than the former one. It is interesting also to analyze what happens in reciprocal space. Then the Peierls substitution amounts to replace \mathbf{k} by $\mathbf{k} - e\mathbf{A}/\hbar$ and the non-vanishing A^2 contributions appear only if $f(\mathbf{k})$ is expanded up to k^2 terms. In the context of studies on graphene, this corresponds to including so-called warping effects. In the context of $\mathbf{k} \cdot \mathbf{p}$ methods such effects would also appear if coupling with other conduction and valence bands are included.⁵⁶

3. One- and two-photon absorption in bulk h -BN

As mentioned previously and, as far as the band structure is concerned, the extension to three dimensional stackings of BN layers is fairly simple. On the other hand the excitonic formalism should also be extended to the case where there are several atoms per unit cell. In practice, if we continue to define exciton states using the separation between electrons and holes, we must add labels indicating in which type of plane they are. The general corresponding TB formalism is described elsewhere,³⁴ but if we are interested in the ground state excitons, the discussion becomes simpler. Actually the $1s$ exciton of the monolayer remains confined within a single plane in bulk h -BN if the hole is fixed in this plane.³⁰ Along the $0z$ stacking direction we have therefore to treat a problem similar to that of a Frenkel exciton, where the 2D exciton plays the part of an atomic excitation. We can then build two different excitonic Bloch functions along the $0z$ stacking direction which we call $|\Phi_A\rangle$ and $|\Phi_{A'}\rangle$. Introducing interplanar transfer integrals in the TB model couples these two states, and since there is an inversion center between any pair of A and A' planes the final exciton eigenstates should be the usual bonding and antibonding states $|\Phi_A\rangle \pm |\Phi_{A'}\rangle$. The $1s$ state of the monolayer becomes two split states (Davydov splitting) separated by a small energy (see also Ref.[34 and 57]). *Ab initio* calculations show that the bonding state is the

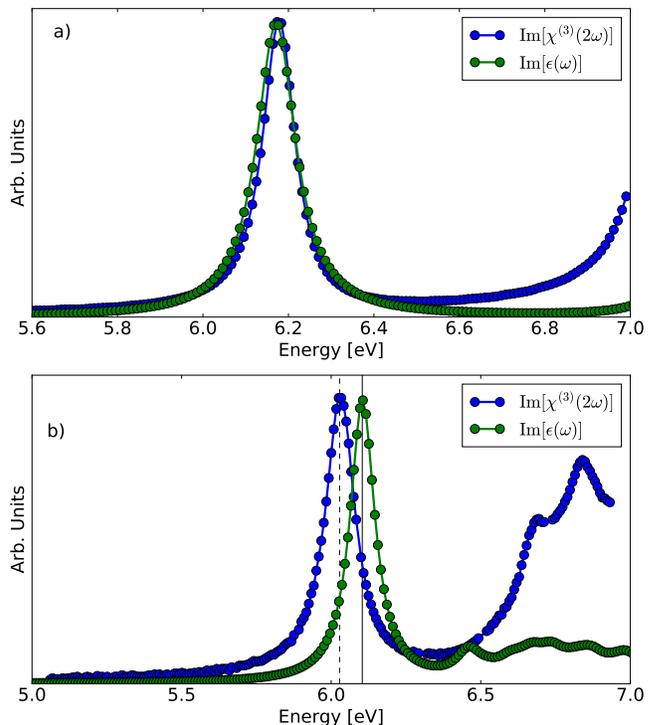


FIG. 1. Two-photon absorption and imaginary part of the dielectric constant in single layer (panel a) and bulk h -BN (panel b), obtained from real-time *ab initio* dynamics. The two curves have been rescaled in such a way to have the same intensity at the maximum position. Vertical lines in panel (b) indicates the position of the maximum.

ground state. Since the threefold symmetry is preserved, the two states are still themselves twofold degenerate.

Let us now look at the one-photon absorption process. We still consider a polarization \mathbf{e} parallel to the planes. The total \mathbf{d}_{Φ} dipole for the AA' stacking is therefore equal to $\mathbf{d}_{\Phi_A} \pm \mathbf{d}_{\Phi_{A'}}$. On the other due to the inversion symmetry $\mathbf{d}_{\Phi_{A'}} = -\mathbf{d}_{\Phi_A}$ and finally the dipole vanishes for the bonding state whereas the upper anti-bonding state is bright. In the case of the two-photon process, we can use a similar argument, but since now $\bar{\mathbf{q}}_{\Phi_{A'}} = \bar{\mathbf{q}}_{\Phi_A}$, the situation is reversed: the bright exciton is the lower bonding one.

IV. RESULTS AND DISCUSSION

A. *ab initio* calculations

All operators in Eq. (12) and Eq. (19) are expanded in the basis set of the Kohn-Sham band states which can be obtained from a standard DFT code. Specifically, we used the QUANTUM ESPRESSO code⁵⁸ where the wavefunctions are expanded in plane waves with a cutoff of 60 Ry and the effect of core electrons is simulated by norm-conserving pseudopotentials. A $12 \times 12 \times 4$ ($12 \times 12 \times 1$ for the single layer) \mathbf{k} -point shifted grid has

been used to converge the electronic density. The band states are obtained from the diagonalization of the Kohn-Sham eigensystem. In order to simulate an isolated h -BN layer we used a supercell approach with a layer-layer distance of 20 a.u. in the perpendicular direction. The scissor operator entering Eq. (19) is chosen so as to reproduce the position of the first bright excitons in the absorption spectra of bulk and monolayer h -BN from Ref.[31].

We expanded $|v_{m\mathbf{k}}\rangle$ in terms of Kohn-Sham eigenstates and we evolved the coefficients of the bands between 2 and 7 in the monolayer (7 and 12 in the bulk) in Eq. (12). The dielectric constant that enters in the calculation of Σ_{SEX} was calculated using 40 bands and 3 Ha cutoff both for the bulk and the monolayer. We used a $15 \times 15 \times 5$ ($12 \times 12 \times 1$ in the single layer) \mathbf{k} -points Γ -centred sampling in the real-time simulations which guarantee the convergence of the first peak in the spectra.⁵⁹ Equation 12 is solved numerically⁶⁰ for a time interval of 120 fs using the numerical approach described in Ref. [48](originally taken from Ref. [61]) with a time step of $\Delta t = 0.01$ fs, which guarantees for numerically stable and sufficiently accurate simulations. A dephasing term corresponding to a finite broadening of about 0.05 eV is introduced in order to simulate the experimental broadening.¹⁷

In Figure 1, panel (a), the two-photon resonant third-order susceptibility at $\chi_{yyyy}^{(3)}(-\omega; \omega, \omega, -\omega)$ proportional to the TPA is compared with the imaginary part of the dielectric constant $\epsilon_2(\omega)$ for the monolayer h -BN. To facilitate the comparison there is a factor 2 between the energy scale of the spectra. The first peak of the TPA is found exactly at half the photon energy of the first peak of the imaginary part of the dielectric constant. That means that the two- and one-photon absorption are resonant with the same exciton. In panel (b) the same comparison is shown for bulk h -BN. In this case the first peak of the TPA is found 0.076 eV below half the photon energy of the first peak of ϵ_2 . That means that the two-photon absorption is resonant with an exciton at lower energy than the one of one-photon absorption. We also obtained $\epsilon_2(\omega)$ by solving the standard GW +Bethe-Salpeter equation⁶² and diagonalized the excitonic two-particle Hamiltonian. We found—in agreement with previous studies³² that the lowest exciton in the linear optical response of bulk h -BN is indeed dark. The position of this dark exciton is consistent with the splitting deduced from the TPA calculations. The *ab initio* results are then fully consistent with the discussion in Sec. III B 3. In the monolayer the ground state exciton is visible in both one-photon and two photon absorption. Instead, in bulk AA' BN, the lowest exciton (pair) is dark in linear optics but becomes visible in two photon absorption. In fact, as explained in Sec. III B 3, the two lowest exciton pairs in the bulk are due to the bonding and anti-bonding combination of excitons in each layer and thus obey different selection rules.

Experimentally, the TPA has been investigated for bulk h -BN in Ref. 8 by two-photon photoluminescence

excitation (PLE) spectroscopy. In agreement with our results, the lowest peaks in one- and two- photons PLE spectra do not coincide, indicating they correspond to different excitons. However, the peak in the one-photon PLE is below the peak in the two-photon PLE spectrum, apparently contradicting our findings. On the other hand, the experimental results indicate as well that phonons are playing a crucial role and the peak in the two-photon PLE spectrum is interpreted as a *phonon-assisted* two-photon absorption which could explain the difference with our simulations which do not include phonon scattering. Considering the possible phonon modes that can contribute to phonon assisted two-photon excitations, we estimate a shift of 150 meV that could indeed account for the observed difference. In Sec. IV C we further discuss these experimental results and their interpretation in connection with the selection rules.

Finally, broader features at higher energies are visible in the spectra. Those features are known to originate from both in-plane excitons with different symmetries¹⁴ and from interplanar excitations. Notice that those peaks may not be fully converged with the parameters of the simulation.⁶³

B. Tight-binding calculations

1. Monolayer

In the case of the monolayer we have used the TB hamiltonian (7) with the parameters determined in Ref.[14] and have calculated the one-photon absorption spectrum from the Green function $\langle I|G(z)|I\rangle, |I\rangle = \sum_{\boldsymbol{\tau}}(\boldsymbol{\tau} \cdot \mathbf{e})|\boldsymbol{\tau}\rangle$, which is actually independent of the choice for \mathbf{e} . This is conveniently done using the recursion method. A cluster of $4 \cdot 10^4$ atoms is used and 100 recursion levels are calculated. The spectrum, proportional to the imaginary part of the optical dielectric constant is also proportional to the imaginary part of the Green function. In the presence of excitonic effects the excitons appear as bound states below the continuum. We have checked that they appear at the same positions as those determined from a full diagonalization of the hamiltonian.¹⁴ Furthermore by comparing the optical spectrum to that obtained from a Green function matrix element without any particular symmetry (here $\langle \boldsymbol{\tau}|G|\boldsymbol{\tau}\rangle$) so that all excitons have a finite weight, we can check the selection rules: the non degenerate exciton of symmetry A_1 is actually dark in the optical response (Fig. 2).

In the case of two-photon absorption, the calculation of the main contribution due to H_{I2} , the quadratic term in A , can be calculated in a similar way; it suffices to modify the matrix element of the Green function, by taking as initial vector $|I'\rangle = \sum_{\boldsymbol{\tau}}(\boldsymbol{\tau} \cdot \mathbf{e})^2|\boldsymbol{\tau}\rangle$. The ground state exciton is then found to be bright as expected. This is in agreement with the *ab initio* spectrum in Fig. 1a where the lowest peak in the TPA and optical absorption coincides.

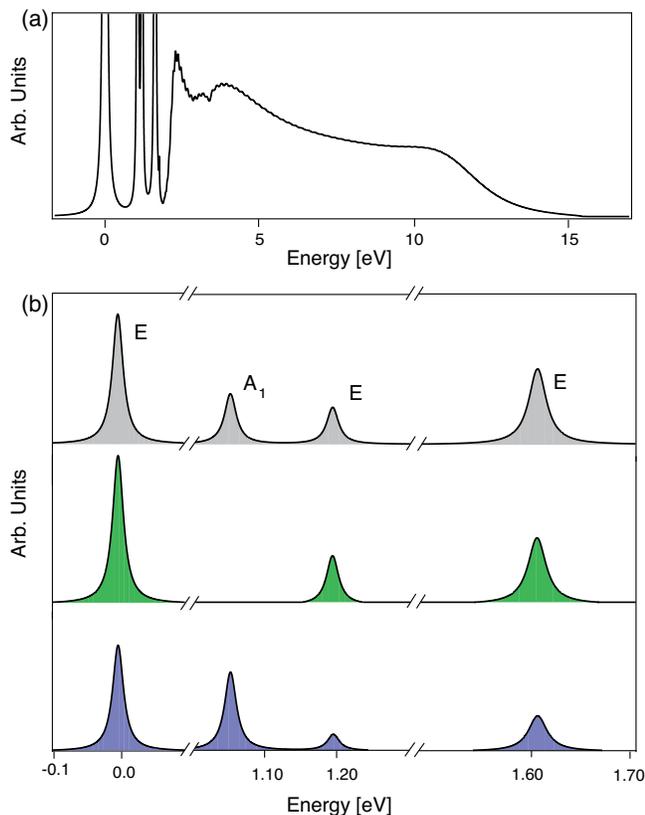


FIG. 2. a) Excitonic joint density of state of the 2D BN monolayer; b) zoom in the exciton region; top: excitonic joint density; middle: one-photon optical spectrum; bottom: two-photon optical spectrum. For convenience a broadening of 10^{-2} eV has been applied, via the imaginary part of z in the Green functions. The A_1 exciton is only dark in the one-photon spectrum. The origin of the energy scale is taken at the position of the lowest exciton, which can also be labelled as a $1s$ exciton whereas the other ones derive from $2s$ and $2p$ states. Full *ab initio* calculations including exchange effects predict the A_1 level to be at a higher energy.¹⁴

2. Bulk AA'

We have generalised the TB formalism to the 3D AA' stacking. Once the appropriate hamiltonian is defined the recursion method can again be used. Here, the cluster considered contains $8 \cdot 10^4$ atoms and 100 recursion levels are calculated. According to our previous discussion, to study the two split ground state excitons we have now to use starting states $|I\rangle$ which are bonding and antibonding combinations of excitons in A and A' planes. The results are shown in Figs. 3. We find that the lower bonding state is dark for one-photon absorption and bright for two-photon absorption, and conversely for the upper antibonding state. Both the excitons position (with respect to the lowest exciton) and Davydov splitting agree with the *ab initio* results (panel b of Fig. 1). In fact, in both calculations the lowest exciton of the TPA spectrum is about 0.1 eV below the lowest exciton of the absorption spectrum. Further, in the TB calculations a second peak is visible in the TPA at about 0.3 eV above the low-

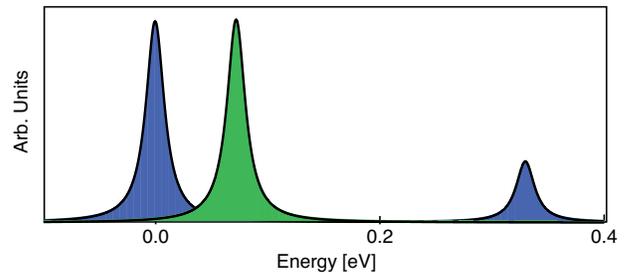


FIG. 3. One- (green) and two-photon (blue) absorption spectrum of AA' h -BN. The results are in agreement with the *ab initio* results in Fig. 1b.

est peak. Similarly, in the *ab initio* TPA spectrum a strong feature is visible at about 0.5 eV above the lowest peak which is absent in the absorption spectrum. This 0.2 eV difference can be attributed to the neglect of the exchange term in the TB model. In fact, an underestimation of the energy of higher excitations has also been also observed for this model in Ref. 14. As well, as we remarked before, the position of higher peaks in the *ab initio* spectra may not be fully converged with the parameters of the simulation, though improving the convergence parameters would likely increase the difference between the TB and *ab initio* results rather than reduce it.⁶⁴

To summarize, the two approaches show consistently that the ground state exciton, which is usually labelled as $1s$ exciton, is bright in both the monolayer and bulk TPA spectra. For the bulk, the comparison between the one-photon and two-photon spectra provides a measure of the Davydov splitting between the two $1s$ excitons which we estimate to be $\lesssim 0.1$ eV.

C. Selection rules

Let us summarize the selection rules which apply to h -BN as well as to TMD. We will briefly discuss the hydrogenic model, that although inadequate,¹⁰ is the first approximation used to interpret optical spectra, then we consider the full symmetry of h -BN.

1. One-photon selection rules

We consider first the case of the monolayer and Wannier-Mott excitons within the continuous hydrogenic model. The exciton wave function is written in the form $\Phi(\mathbf{r}_h, \mathbf{r}_e) = \phi_{\mathbf{k}_0 c}(\mathbf{r}_e) \phi_{\mathbf{k}_0 v}(\mathbf{r}_h) g(\mathbf{r}_e - \mathbf{r}_h)$, where the $\phi_{\mathbf{k}_0}$ are the single particle Bloch functions at point \mathbf{k}_0 corresponding to the considered direct gap, and $g(\mathbf{r})$, the envelope function, is the solution of the hydrogenic-like excitonic equation. Optical one-photon transitions are then only allowed for s states. On the other hand the direct optical transition is allowed since the standard matrix element varies as $v_F(e_x \pm ie_y)$ (see Eq.(5)), corresponding

to polarizations σ_{\pm} , depending on the valley K or K' . These rules are weakened if the dependence on \mathbf{k} of the matrix elements is taken into account.¹⁶

The excitonic states characterized by the wave function $\Phi_{\mathbf{R}} = \langle \mathbf{R} | \Phi^{\pm} \rangle$ for the monolayer can then be classified according to the representations of the C_{3v} point group. Among the three representations A_1, A_2 and E , only the two-dimensional representation E is optically active, as discussed in Section IID. Let us precise the correspondence between the continuous description in terms of s, p, \dots states characterising the symmetry of the envelope function and the present description using the discrete crystal symmetry. For that, we have to include the symmetry of the product of $\phi_{\mathbf{k}_{0c}}(\mathbf{r}_e)\phi_{\mathbf{k}_{0v}}(\mathbf{r}_h)$ at K point. The relevant group of vector \mathbf{K} is the C_3 point group so that in our case this product is multiplied by $e^{\pm 2i\pi/3}$ under a rotation of $\pm 2\pi/3$. For a level of symmetry characterized by an angular momentum m , the envelope function of the corresponding exciton states varies as $e^{\pm im\varphi}$.

When $m \neq 0$ the level is twofold degenerate and the full wave function varies as $e^{i(1\pm m)\varphi}$. The same is true at K' point provided φ is changed into $-\varphi$. So finally the level shows a fourfold degeneracy. Since the crystal symmetry is lower than the continuous symmetry the degeneracy is lifted. Consider the p states for example ($m = \pm 1$). It has been shown in Ref.[14] that the four p levels decompose according to the $E + A_1 + A_2$ representations. These rules are fairly well-known^{11,13-16} but have been recently re-discovered and discussed in detail.^{65,66}

Then, if intervalley coupling is accounted for, the ± 1 states combine to produce a global E symmetry, whereas the $m_{\text{tot}} = 0$ states combine to form A_1 and A_2 states. Now, only E states are one-photon bright, since the velocity also transforms as E . The ground state $1s$ exciton is obviously bright and forms an E state with a very strong oscillator strength, but we see that the $2p$ states give rise also to a bright exciton.

Consider now the bulk AA' stacking. According to the discussion given in Section IIIB3, we have just to consider a linear superposition of monolayer E states. For this stacking this gives rise to Davydov pairs of bonding and antibonding states, and only antibonding states are bright. There are therefore two types of selection rules for such lamellar structures for a polarization in the planes. The first one ensures the existence of a dipole within the planes while the second depends on the constructive or destructive arrangement of the dipoles in the stacking.

2. Two photon selection rules

Within the continuous model, the general statement concerning selection rules is that only p states are visible, corresponding to $\nabla g(\mathbf{r}) \neq 0$.¹² What is changing here is the symmetry of the coupling with light which has now a tensorial character and varies therefore as $e^{\pm i\varphi}e^{\pm i\varphi}$ for the monolayer. If the rule of m modulo 3 is added, this

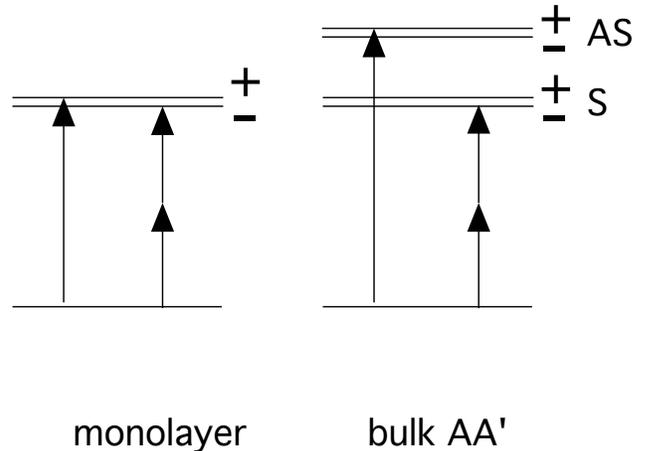


FIG. 4. Allowed transitions towards the lowest excitonic states with circularly polarized light. Left: Monolayer; the $\Phi^+(\Phi^-)$ is excited with a one-photon (two-photon) process, where Φ^{\pm} denote the two circularly components of the degenerate $1s$ exciton. Right: Bulk AA' stacking; there are now two antisymmetric (AS, odd, one-photon allowed) and symmetric (S, even, two-photon allowed) degenerate states, separated by a Davydov splitting.

means that all m_{tot} values are allowed. In the discrete case, it varies as $E \otimes E = E + A_1 + A_2$ which indicates also that all excitons are in principle bright. We have seen in particular that the oscillator strength for the ground state $1s$ exciton is found actually to be very strong. In the case of the bulk AA' stacking, the bright excitons in the Davydov pairs are the bonding states. This is a familiar selection rule: In the presence of a symmetry center odd (even) states are one(two)-photon allowed. Then the difference with the one-photon selection rules is less important than in the usual continuous model, but at least in the case of the AA' stacking combining both processes can be used to discriminate between the components of the Davydov doublets (Fig.4). The two-photon selection rules for the monolayer agree with those derived by Xiao et al.¹³ who, however, do not discuss the possibility of the splitting of $2p$ states. Since they consider only circular polarizations, they do not discuss either the possibility of exciting $m = 0$ (or A_1, A_2) states, but the corresponding oscillator strengths should be weak since they imply intervalley interactions.

3. Experimental results

One of our main result is the prediction that the ground state $1s$ exciton which is bright in one-photon absorption should be bright also in two-photon processes, with opposite circular polarizations. The best experimental evidence is certainly the observation in TMD of resonant second harmonic generation (SHG).⁶⁷⁻⁶⁹ In the absence of symmetry center, SHG is allowed for

a dichalcogenide layer and it is actually found to be strongly resonant when the $1s$ level is excited in a two-photon process. Furthermore the circular polarization of the 2ω emission is actually opposite to that of the excitation.^{13,70} In the case of h -BN only two-photon PLE spectra are available for the bulk phase.⁸ As already commented in Sec. IV A, they do show a peak slightly above the one-photon main peak whereas we predict a peak below it. The situation is complicated by the fact that the gap is indirect. This is important for the interpretation of luminescence spectra but it is suspected that absorption spectra are governed by direct transitions.³³ The difference between one-photon and two-photon spectra has been interpreted as the signature of s and p states respectively. The present analysis show that this is probably not true because of the non conventional selection rules. Another argument is that the $2p$ and $2s$ are predicted to be well above the $1s$ states (about 1 eV for the monolayer, 0.5 eV for the bulk) and cannot therefore be involved in the observed splitting.⁷¹ But the precise interpretation of the observed splitting remains to be correlated with the calculated Davydov splitting. To summarize, we have performed TB and *ab initio* calculations of two-photon absorption in monolayer and bulk boron nitride and found that at low energy the spectra are dominated by excitonic effects. The ground state $1s$ exciton is predominant—as for one-photon absorption—indicating strong deviations from the selection rules based on the hydrogenic model which are frequently employed to interpret the experimental spectra. For both the bulk and 2D case, we have explained the selection rule within a simple TB model that takes into account the crystalline symmetry. Finally, the result obtained for the bulk indicates that one can measure the Davydov splitting in multilayer stackings with inversion symmetry of h -BN and 2D crystals with the same point-group symmetry.

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Appendix A: On the equivalence of length and velocity gauge in tight-binding

Optical properties are usually treated using the so-called velocity gauge: \mathbf{p} is replaced by $\mathbf{p} - e\mathbf{A}$. As discussed in the main text this implies that to calculate the response to second order in \mathbf{A} we have to calculate a first order perturbation term in A^2 and a second order perturbation term with respect to \mathbf{A} . In the length gauge where the interaction term in the hamiltonian is equal to $e\mathbf{r}\cdot\mathcal{E}$, there is no quadratic term. Since approximations are made, it is useful to check gauge invariance. If we refer to the discussion made in the velocity gauge in Section III B 1 we have therefore just to calculate the second order perturbation term proportional to $\Delta\langle\Phi|(\mathbf{r}\cdot\mathbf{e})(\mathbf{r}\cdot\mathbf{e})|\emptyset\rangle$. We have used the fact that $\mathcal{E} = i\omega\mathbf{A}$ and that $\omega \simeq \Delta$. The first \mathbf{r} generates electron-hole pairs $\mathbf{r}_{\mathbf{nm}}a_{\mathbf{n}_c}^+a_{\mathbf{m}_v}|\emptyset\rangle$. To lowest order in t/Δ , $\mathbf{r}_{\mathbf{nm}}$ vanishes, and we must use the improved Wannier basis defined in Eqs (1-2), and then $\mathbf{r}_{\mathbf{nm}} \simeq -(t/2\Delta)(\mathbf{n} - \mathbf{m})$, where $(\mathbf{n} - \mathbf{m})$ is a first neighbor vector $\boldsymbol{\tau}$, so that:

$$\mathbf{r}|\emptyset\rangle \simeq -\frac{t}{2\Delta} \sum_{\boldsymbol{\tau}} \boldsymbol{\tau}|\boldsymbol{\tau}\rangle$$

The second \mathbf{r} operator connects intraband conduction and valence states, and to lowest order in t/Δ it can be checked that $\mathbf{r}|\boldsymbol{\tau}\rangle \simeq \boldsymbol{\tau}|\boldsymbol{\tau}\rangle$, so that, finally:

$$\Delta\langle\Phi|(\mathbf{r}\cdot\mathbf{e})(\mathbf{r}\cdot\mathbf{e})|\emptyset\rangle \simeq -\frac{t}{2} \sum_{\boldsymbol{\tau}} (\boldsymbol{\tau}\cdot\mathbf{e})^2 \Phi_{\boldsymbol{\tau}}^{\pm},$$

which is exactly the result derived in Eq.(25). Thus to lowest order, the second order perturbation theory in the length gauge reproduces the first order term as a function of $(\mathbf{A}\cdot\mathbf{e})^2$ in the velocity gauge. The general equivalence of both gauges for non-linear responses of higher order has also been discussed recently in Ref. [72].

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